
HVC135

Silicon Epitaxial Trench Pin Diode for Antenna Switching

HITACHI

ADE-208-818A (Z)

Rev. 1
Feb. 2000

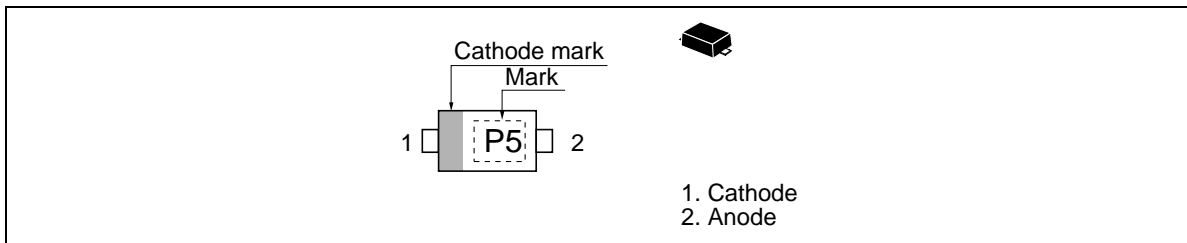
Features

- Adopting the trench structure improves low capacitance. ($C=0.6\text{pF}$ max)
- Low forward resistance. ($r_f=2.0\Omega$ max)
- Low operation current.
- Ultra small Flat Package (UFP) is suitable for surface mount design and stable rf characteristics in high frequency.

Ordering Information

| Type No. | Laser Mark | Package Code |
|----------|------------|--------------|
| HVC135 | P5 | UFP |

Outline



HVC135

Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Value | Unit |
|----------------------|----------|-------------|------|
| Peak reverse voltage | V_{RM} | 65 | V |
| Reverse voltage | V_R | 60 | V |
| Forward current | I_F | 100 | mA |
| Power dissipation | P_d | 150 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature | Tstg | -55 to +125 | °C |

Electrical Characteristics

(Ta = 25°C)

| Item | Symbol | Min | Typ | Max | Unit | Test Condition |
|-----------------------------|--------|-----|-----|-----|------|---|
| Reverse current | I_R | — | — | 0.1 | μA | $V_R = 60V$ |
| Forward voltage | V_F | — | — | 0.9 | V | $I_F = 2\text{ mA}$ |
| Capacitance | C | — | — | 0.6 | pF | $V_R = 1V, f = 1\text{ MHz}$ |
| Forward resistance | r_f | — | — | 2.0 | Ω | $I_F = 2\text{mA}, f = 100\text{ MHz}$ |
| ESD-Capability ¹ | — | 100 | — | — | V | C = 200pF , Both forward and reverse direction 1 pulse. |

Notes 1. Failure criterion ; $I_R > 100\text{nA}$ at $V_R = 60\text{ V}$

Main Characteristic

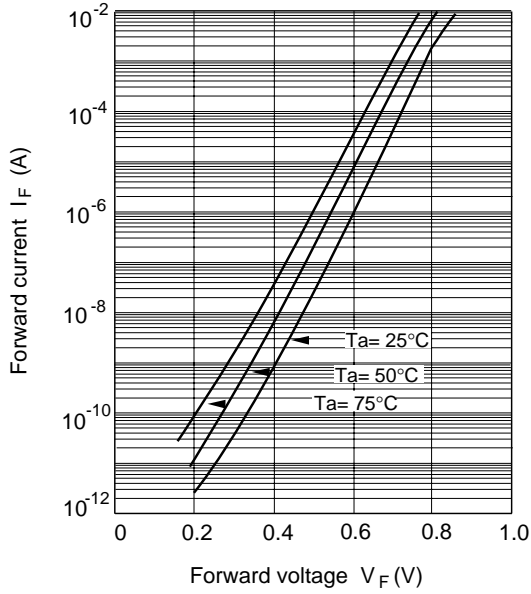


Fig.1 Forward current Vs. Forward voltage

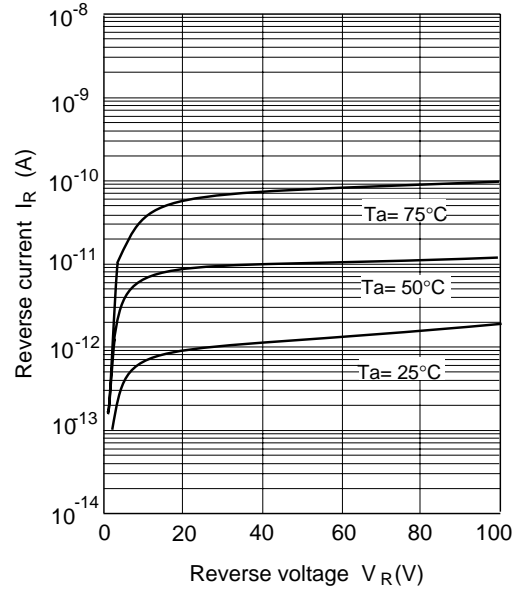


Fig.2 Reverse current Vs. Reverse voltage

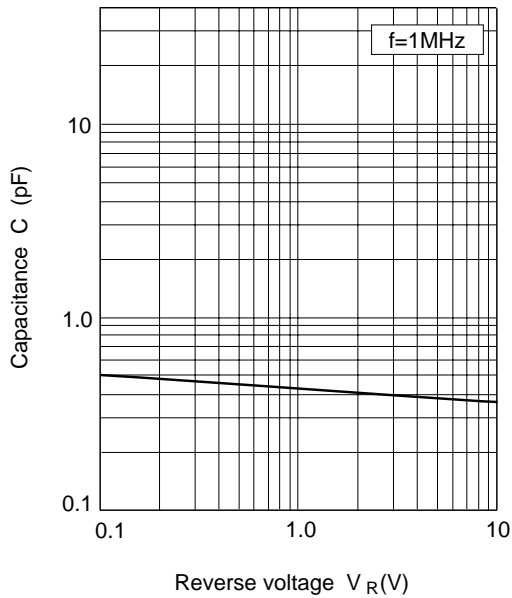


Fig.3 Capacitance Vs. Reverse voltage

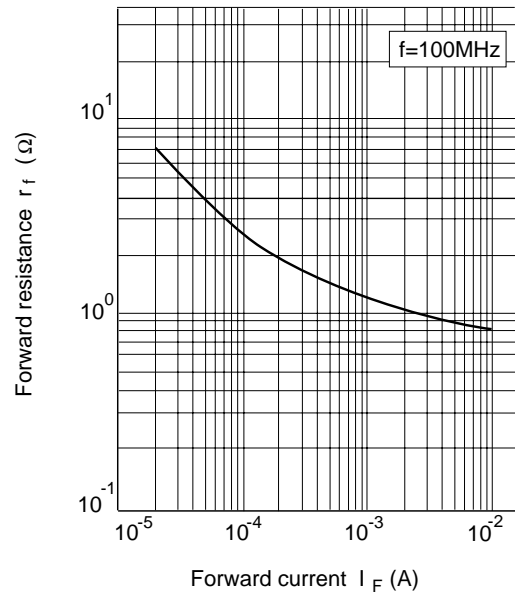


Fig.4 Forward resistance Vs. Forward current

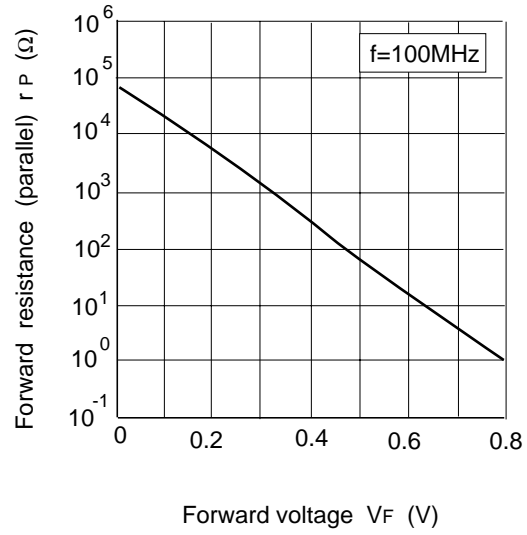
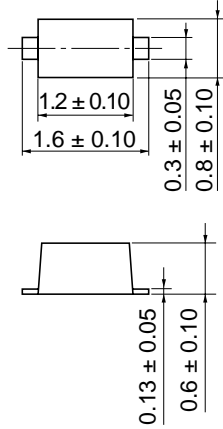
Main Characteristic

Fig.5 Forward resistance (parallel) Vs. Forward voltage

Package Dimensions

Unit: mm



| | |
|--------------|----------|
| Hitachi Code | UFP |
| JEDEC | — |
| EIAJ | Conforms |
| Mass | 0.0016 g |

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